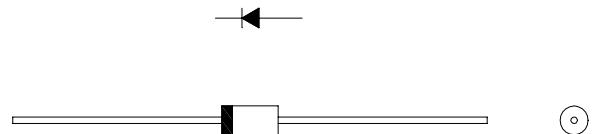


# DIODE Type : 20E2

## OUTLINE DRAWING

### FEATURES

- \* Miniature Size
- \* Low Forward Voltage drop
- \* Low Reverse Leakage Current
- \* High Surge Capability
- \* 52mm Inside Tape Spacing Package Available



### Maximum Ratings

Approx Net Weight:0.38g

Rating	Symbol	20E2			Unit	
Repetitive Peak Reverse Voltage	$V_{RRM}$	200			V	
Non-repetitive Peak Reverse Voltage	$V_{RSM}$	400			V	
Average Rectified Output Current	$I_o$	1.3	Ta=33°C *1	50Hz Half Sine Wave Resistive Load	A	
		1.7	Ta=43°C *2			
RMS Forward Current	$I_{F(RMS)}$	2.67			A	
Surge Forward Current	$I_{FSM}$	80	50Hz Half Sine Wave, 1cycle, Non-repetitive			
Operating JunctionTemperature Range	$T_{jw}$	- 40 to + 150			°C	
Storage Temperature Range	$T_{stg}$	- 40 to + 150			°C	

### Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions		Min.	Typ.	Max.	Unit
Peak Reverse Current	$I_{RM}$	$T_j = 25^\circ\text{C}$ , $V_{RM} = V_{RRM}$		-	-	10	μA
Peak Forward Voltage	$V_{FM}$	$T_j = 25^\circ\text{C}$ , $I_{FM} = 1.7\text{A}$		-	-	0.92	V
Thermal Resistance	$R_{th(j-a)}$	Junction to Ambient		*1	-	105	°C/W
				*2		70	

\*1 : Without Fin or P.C. Board

\*2 : P.C. Board Mounted (L=8mm, Print Land=15 x 15mm, Both Sides)

20E2 OUTLINE DRAWING (Dimensions in mm)

